

Small Signal Diode



Features

- ◊ Wide zener voltage range selection : 2.4V to 75V
- ◊ Surface device type mounting
- ◊ Moisture sensitivity level 1
- ◊ Matte Tin(Sn) lead finish with Nickel(Ni) underplate
- ◊ Pb free version, RoHS compliant
- ◊ Green compound (Halogen free) with suffix "G" on packing code and prefix "G" on date code

Mechanical Data

- ◊ Case : SOD-523F small outline plastic package
- ◊ Terminal: Matte tin plated, lead free., solderable per MIL-STD-202, Method 208 guaranteed
- ◊ High temperature soldering guaranteed: 260°C/10s
- ◊ Polarity : Indicated by cathode band
- ◊ Weight : 1.68±0.5 mg

Ordering Information

Part No.	Package code	Package	Packing
BZT52C2V4K~75K	RK	SOD-523F	3K / 7" Reel
BZT52C2V4K~75K	RKG	SOD-523F	3K / 7" Reel

Maximum Ratings and Electrical Characteristics

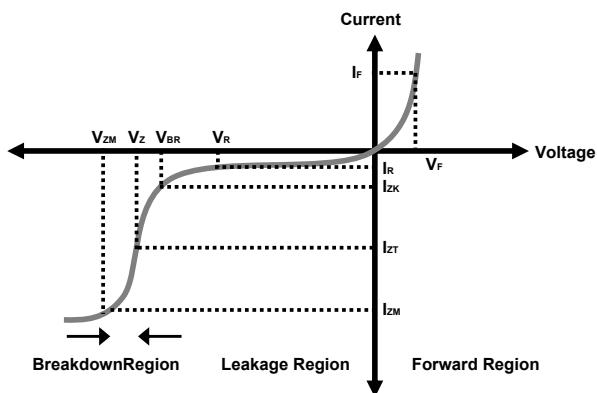
Rating at 25°C ambient temperature unless otherwise specified.

Maximum Ratings

Type Number	Symbol	Value	Units
Power Dissipation	P_D	200	mW
Forward Voltage $I_F=10\text{mA}$	V_F	1	V
Thermal Resistance (Junction to Ambient) (Note 1)	$R_{\theta JA}$	625	°C/W
Junction and Storage Temperature Range	T_J, T_{STG}	-55 to + 150	°C

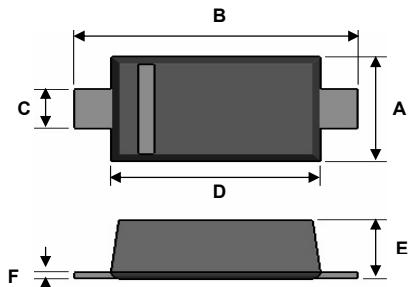
Notes:1. Valid provided that electrodes are kept at ambient temperature

Zener I vs. V Characteristics



BZT52C2V4K~BZT52C75K 200mW, Surface Mount Zener Diode

SOD-523F

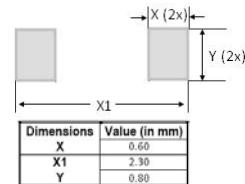


Dimensions	Unit (mm)		Unit (inch)	
	Min	Max	Min	Max
A	0.70	0.90	0.028	0.035
B	1.50	1.70	0.059	0.067
C	0.25	0.40	0.010	0.016
D	1.10	1.30	0.043	0.051
E	0.60	0.70	0.024	0.028
F	0.10	0.14	0.004	0.006

Pin Configuration



Suggested PAD Layout



- V_{BR} : Voltage at I_{ZK}
 I_{ZK} : Test current for voltage V_{BR}
 Z_{ZK} : Dynamic impedance at I_{ZK}
 I_{ZT} : Test current for voltage V_Z
 V_Z : Voltage at current I_{ZT}
 Z_{ZT} : Dynamic impedance at I_{ZT}
 I_{ZM} : Maximum steady state current
 V_{ZM} : Voltage at I_{ZM}

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Electrical Characteristics

T_a = 25°C unless otherwise noted

V_F Forward Voltage = 1V Maximum @ I_F = 10 mA for all part numbers

Part Number	Device Marking	V _Z @ I _{ZT} (Volt)			I _{ZT} (mA)	Z _{ZT} @ I _{ZT} (Ω) Max	I _{ZK} (mA)	Z _{ZK} @ I _{ZK} (Ω) Max	I _R @ V _R (μA) Max	V _R (V)
		Nom	Min	Max						
BZT52C2V4K	50	2.2	2.4	2.6	5	100	1	1000	50	1
BZT52C2V7K	51	2.5	2.7	2.9	5	100	1	1000	20	1
BZT52C3V0K	52	2.8	3	3.2	5	100	1	1000	10	1
BZT52C3V3K	53	3.1	3.3	3.5	5	95	1	1000	5	1
BZT52C3V6K	54	3.4	3.6	3.8	5	90	1	1000	5	1
BZT52C3V9K	55	3.7	3.9	4.1	5	90	1	1000	3	1
BZT52C4V3K	56	4	4.3	4.6	5	90	1	1000	3	1
BZT52C4V7K	57	4.4	4.7	5	5	80	1	800	3	2
BZT52C5V1K	58	4.8	5.1	5.4	5	60	1	500	2	2
BZT52C5V6K	59	5.2	5.6	6	5	40	1	200	1	2
BZT52C6V2K	5A	5.8	6.2	6.6	5	10	1	100	3	4
BZT52C6V8K	5B	6.4	6.8	7.2	5	15	1	160	2	4
BZT52C7V5K	5C	7	7.5	7.9	5	15	1	160	1	5
BZT52C8V2K	5D	7.7	8.2	8.7	5	15	1	160	0.7	5
BZT52C9V1K	5E	8.5	9.1	9.6	5	15	1	160	0.2	7
BZT52C10K	5F	9.4	10	10.6	5	20	1	160	0.1	8
BZT52C11K	5G	10.4	11	11.6	5	20	1	160	0.1	8
BZT52C12K	5H	11.4	12	12.7	5	25	1	80	0.1	8
BZT52C13K	5J	12.4	13	14.1	5	30	1	80	0.1	8
BZT52C15K	5K	14.3	15	15.8	5	30	1	80	0.05	10.5
BZT52C16K	5L	15.3	16	17.1	5	40	1	80	0.05	11.2
BZT52C18K	5M	16.8	18	19.1	5	45	1	80	0.05	12.6
BZT52C20K	5N	18.8	20	21.2	5	55	1	100	0.05	14
BZT52C22K	5P	20.8	22	23.3	5	55	1	100	0.05	15.4
BZT52C24K	5R	22.8	24	25.6	5	70	1	120	0.05	16.8
BZT52C27K	5S	25.1	27	28.9	2	80	0.5	300	0.05	18.9
BZT52C30K	5T	28	30	32	2	80	0.5	300	0.05	21
BZT52C33K	5U	31	33	35	2	80	0.5	300	0.05	23.2
BZT52C36K	5V	34	36	38	2	90	0.5	500	0.05	25.2
BZT52C39K	5X	37	39	41	2	130	0.5	500	0.05	27.3
BZT52C43K	5Y	40	43	46	2	150	0.5	500	0.05	30.1
BZT52C47K	5Z	44	47	50	2	170	0.5	500	0.05	32.9
BZT52C51K	5-	48	51	54	2	180	0.5	500	0.05	35.7
BZT52C56K	5=	52	56	60	2	200	0.5	500	0.05	39.2
BZT52C62K	5≡	58	62	66	2	215	0.5	500	0.05	43.4
BZT52C68K	5>	64	68	72	2	240	0.5	500	0.05	47.6
BZT52C75K	5<	70	75	79	2	255	0.5	500	0.05	52.5

Notes:

1. The Zener Voltage (V_Z) is tested under pulse condition of 10ms
2. The device numbers listed have a standard tolerance on the nominal zener voltage of ±2%.
3. For detailed information on price, availability and delivery of nominal zener voltages between the voltages shown and tighter voltage tolerances,
4. The zener impedance is derived from the 60-cycle ac voltage, which results when an ac current having an rms value equal to 10% of the DC zener current

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Rating and Shacteristic Curves

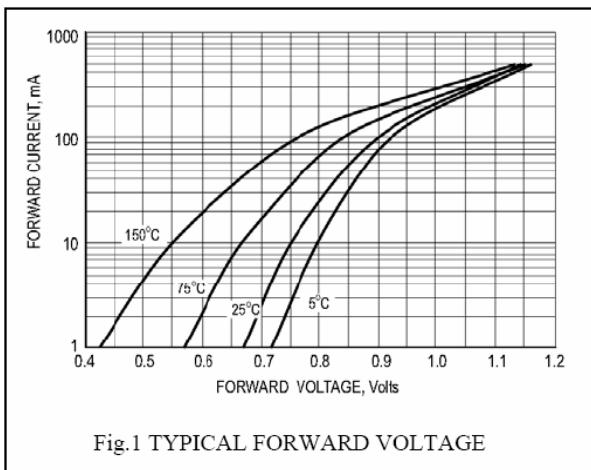


Fig.1 TYPICAL FORWARD VOLTAGE

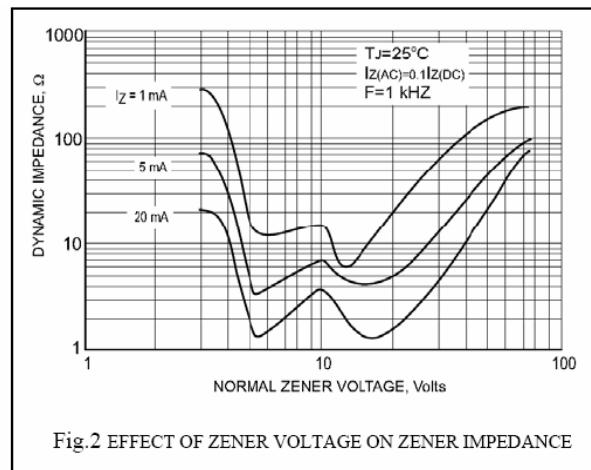


Fig.2 EFFECT OF ZENER VOLTAGE ON ZENER IMPEDANCE

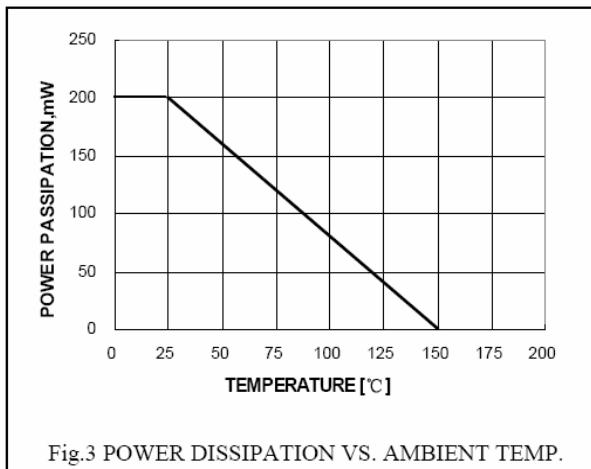


Fig.3 POWER DISSIPATION VS. AMBIENT TEMP.

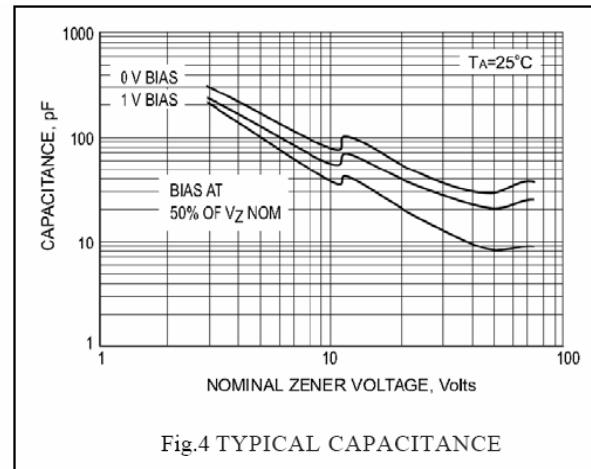


Fig.4 TYPICAL CAPACITANCE

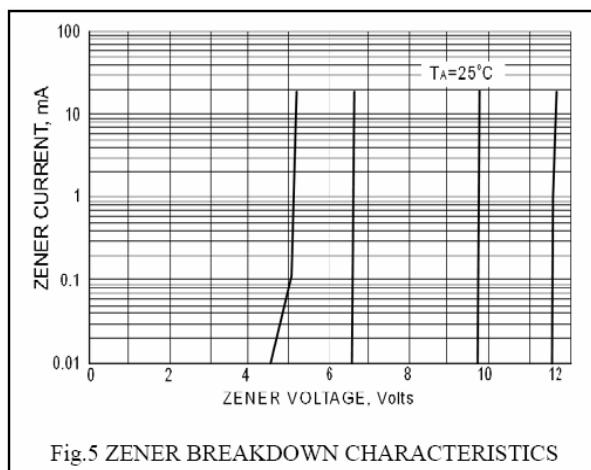


Fig.5 ZENER BREAKDOWN CHARACTERISTICS

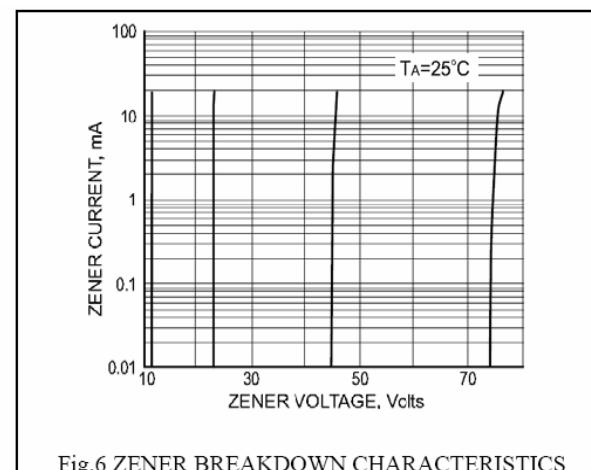


Fig.6 ZENER BREAKDOWN CHARACTERISTICS